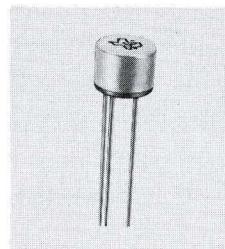


TYPES 2N1273, 2N1274, 2N1370, 2N1371

P-N-P ALLOY-JUNCTION GERMANIUM TRANSISTORS



**Specifically designed for small-signal
audio-amplifiers**



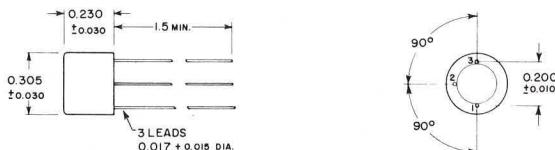
qualification testing

To ensure maximum reliability, stability, and long life, all units are heat cycled from -55°C and room humidity to $+85^{\circ}\text{C}$ and 95% relative humidity for four complete cycles over an eight hour period. All transistors are thoroughly tested for rigid adherence to specified design characteristics on CAT (Central Automatic Testing) equipment.

mechanical data

Metal case with new glass-to-metal hermetic seal between case and leads eliminates all welding and soldering operations from the sealing process. Standard JEDEC E3-51 base, TO-9 package. Approximate unit weight 1 gram.

ALL LEADS INSULATED FROM CASE



ALL DIMENSIONS IN INCHES

maximum ratings at 25°C ambient temperature (unless otherwise noted)

	2N1273	2N1274	2N1370	2N1371	unit
Collector - Base Voltage	15	25	25	45	v
Emitter - Base Voltage	10	10	10	10	v
Collector - Emitter Voltage	15	25	25	45	v
Collector Current	150	150	150	150	ma
Total Device Dissipation	150	150	150	150	mw
Collector Junction Temperature	85	85	85	85	$^{\circ}\text{C}$
Storage Temperature Range	$-55 \text{ to } +85$		$-55 \text{ to } +85$		$-55 \text{ to } +85$

electrical characteristics at 25°C ambient temperature

TEST CONDITIONS

I_{CBO} Collector Reverse Current (max)	$V_{CB} = -12\text{v}$	$I_E = 0$	-14	-14	μa
	(max)	$V_{CB} = -20\text{v}$	$I_E = 0$		
	(typ)	$V_{CB} = -1.5\text{v}$	$I_E = 0$	-3	μa
I_{EBO} Emitter Reverse Current	(typ)	$V_{EB} = -1.5\text{v}$	$I_C = 0$	-3	μa
h_{FE} dc Forward Current Transfer Ratio*	(min)	$V_{CE} = -1.0\text{v}$	$I_C = -50\text{ ma}$	30	50
	(typ)			50	80
	(max)			150	150
V_{BE} Base-Emitter Voltage	(max)	$V_{CE} = -1.0\text{v}$	$I_C = -100\text{ ma}$		0.5
$f_{\alpha C}$ Alpha-Cutoff Frequency	(typ)	$V_{CB} = -5.0\text{v}$	$I_E = 1\text{ ma}$	30	50
Noise Figure	(typ) [†]	$V_{CB} = -5.0\text{v}$	$I_E = 1\text{ ma}$	6.5	2
					mc
					db

*Tolerance on all values $\pm 10\%$ for test set correlation.

[†]Conventional noise compared to 1000 cps and 1 cycle bandwidth.

LICENSED UNDER BELL SYSTEM PATENTS

SEMICONDUCTOR-COMPONENTS DIVISION

TEXAS INSTRUMENTS
INCORPORATED
SEMICONDUCTOR-COMPONENTS DIVISION
P. O. BOX 312 • 13500 N. CENTRAL EXPRESSWAY
DALLAS, TEXAS

TYPES 2N1273, 2N1274, 2N1370, 2N1371
BULLETIN NO. DL-S 1140, AUGUST 1959

TYPES 2N1273, 2N1274, 2N1370, 2N1371

COLOR CODING

Color Dots and Beta Brackets

The transistors are color coded to identify matched pairs for push-pull audio applications. The dc Beta spread is divided into 7 equal brackets such that the maximum current gain variation per bracket is 2 db. Any two units within a bracket constitute a matched pair. The 7 brackets, beta range, and corresponding color codes are indicated below:

Bracket No.	Beta Range*	Color Code
1	30-38	Brown
2	38-50	Red
3	50-60	Orange
4	60-75	Yellow
5	75-95	Green
6	95-120	Blue
7	120-150	Violet

The above bracketing can be utilized to minimize the gain variation in driver-output combinations. The group combinations shown below will match high and low gain units by color code for outstanding uniformity in production amplifiers.

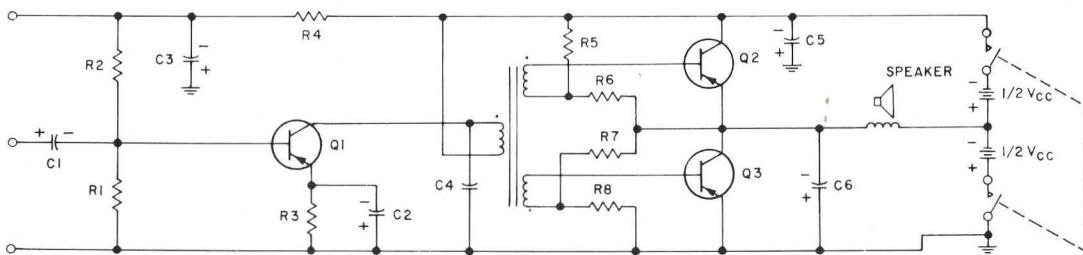
	Combination			
	A	B	C	D
Driver Bracket	4	5	6	7
Output Bracket	4	3	2	1

For additional information regarding the use of this system in audio amplifiers, contact your nearest Texas Instruments field sales office.

*Tolerance on all values $\pm 10\%$ for test set correlation.

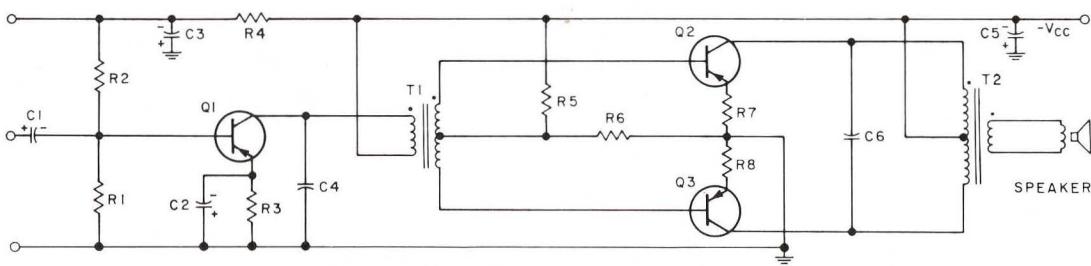
TYPES 2N1273, 2N1274, 2N1370, 2N1371

TYPICAL AMPLIFIER CIRCUITS



PARTS LIST, PUSH-PUSH AMPLIFIER

$V_{CC} = 9\text{ v}$	$C_1 = 5\text{ }\mu\text{f}/3\text{v}$
$R_1 = 4.7\text{ K}$	$C_2 = 100\text{ }\mu\text{f}/3\text{v}$
$R_2 = 27\text{ K}$	$C_3 = 50\text{ }\mu\text{f}/12\text{v}$
$R_3 = 820\text{ ohms}$	$C_4 = 0.002\text{ }\mu\text{f}$
$R_4 = 220\text{ ohms}$	$C_5 = 50\text{ }\mu\text{f}$
$R_5 = 1.2\text{ K}$	$C_6 = 1\text{ }\mu\text{f}/12\text{v}$
$R_6 = 56\text{ ohms}$	Speaker 30 ohms
$R_7 = 1.2\text{ K}$	Q_1, Q_2, Q_3 ; 2N1274 per table
$R_8 = 56\text{ ohms}$	T-1 8.8 K to 50 ohms split



PARTS LIST, PUSH-PULL AMPLIFIER

$V_{CC} = 9\text{ v}$	$C_1 = 5\text{ }\mu\text{f}/3\text{v}$
$R_1 = 4.7\text{ K}$	$C_2 = 100\text{ }\mu\text{f}/3\text{v}$
$R_2 = 33\text{ K}$	$C_3 = 50\text{ }\mu\text{f}/3\text{v}$
$R_3 = 1\text{ K}$	$C_4 = 0.001\text{ }\mu\text{f}$
$R_4 = 220\text{ ohms}$	$C_5 = 50\text{ }\mu\text{f}/12\text{v}$
$R_5 = 3.3\text{ K}$	$C_6 = 0.068\text{ }\mu\text{f}$
$R_6 = 56\text{ ohms}$	Speaker 3.2 ohms
$R_7 = 4.7\text{ ohms}$	Q_1, Q_2, Q_3 ; 2N1274 per table
$R_8 = 4.7\text{ ohms}$	T_1 16.5 K to 1.32 K split
	T_2 366 ohms C.T. to 3.2 ohms

TYPICAL PERFORMANCE DATA

	Push-Pull	Push-Push
Supply Voltage	9v	9v
Rated Power Out	250 mw	250 mw
Power at 10% Distortion	312 mw	300 mw
Distortion at Rated Power	5%	6%
Distortion at 50 mw Power	2%	2%
Input Impedance	1.2 K	1 K
Input voltage for 50 mw		
Power Out	3 mv	4 mv
Power Gain	68 db	65 db
Response Down	130 cps	100 cps
3 db at	5.0 kc	4.5 kc
Battery Drain Zero Out	9.5	7.5 ma
Rated Out	60 ma	48 ma



SEMICONDUCTOR—COMPONENTS DIVISION

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TYPICAL CHARACTERISTICS AND DATA

